NSN 5961-01-287-5655

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.140 inches
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
225.0 reverse voltage, peak
Current Rating Per Characteristic:
400.00 milliamperes forward current, average absolute
Power Rating Per Characteristic:
$600.0 \ milliwatts \ small-signal \ input \ power, \ common-collector \ preset$
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0